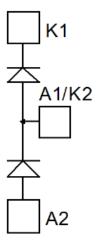
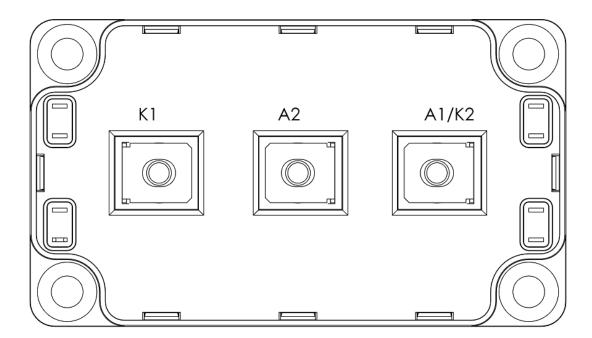


MSCDC450A70AG SiC Diode Phase Leg Power Module

1 Product Overview

This section provides the product overview for the MSCDC450A70AG device.





All ratings at $T_j = 25$ °C, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures should be followed.



1.1 Features

The following are key features of the MSCDC450A70AG device:

- Silicon carbide (SiC) Schottky diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature-independent switching behavior
 - Positive temperature coefficient on VF
- Low stray inductance
- M5 power connectors
- High level of integration
- Aluminum nitride (AIN) substrate for improved thermal performance

1.2 Benefits

The following are benefits of the MSCDC450A70AG device:

- Outstanding performance at high-frequency operation
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS compliant

1.3 Applications

The MSCDC450A70AG device is designed for the following applications:

- Uninterruptible power supply (UPS)
- Induction heating
- Welding equipment
- High-speed rectifiers



2 Electrical Specifications

This section provides the electrical specifications for the MSCDC450A70AG device.

2.1 Absolute Maximum Ratings

The following table shows the absolute maximum ratings per diode for the MSCDC450A70AG device.

Table 1 • Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V _{RRM}	Repetitive peak reverse voltage		700	V
lF	DC forward current	Tc = 55 °C	450	Α

The following table shows the thermal and package characteristics of the MSCDC450A70AG.

Table 2 • Thermal and Package Characteristics

Symbol	Characteristic			Min	Max	Unit
Visol	RMS isolation voltage, any terminal to case t =1 minute, 50 Hz/60 Hz			4000		V
Tı	Operating junction temperature range			-40	175	°C
Тлор	Recommended junction temperature under switching conditions			-40	T _{Jmax} -25	
Тѕтс	Storage temperature range			-40	125	
Tc	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight				300	g

2.2 Electrical Performance

The following table shows the electrical characteristics per diode of the MSCDC450A70AG.

Table 3 • Electrical Characteristics Per Diode

Symbol V _F	Characteristic Diode forward voltage	Test Conditions	Test Conditions		Тур	Max	Unit
		I _F = 450 A	T _j = 25 °C		1.5	1.8	V
			T _j = 175 °C		1.9		=
Irm	Reverse leakage current	V _R = 700 V	T _j = 25 °C		0.13	1.8	mA
			T _j = 175 °C		1.9		=
Q c	Total capacitive charge	V _R = 400 V			1197		nC
С	Total capacitance	f = 1 MHz, V _R = 200 V			2232		pF
		f = 1 MHz, V _R =	400 V		1944		=
RthJC	Junction-to-case thermal resistance					0.114	°C/W



2.3 Performance Curves

This section shows the typical performance curves for the MSCDC450A70AG device.

Figure 1 • Maximum Transient Thermal Impedance

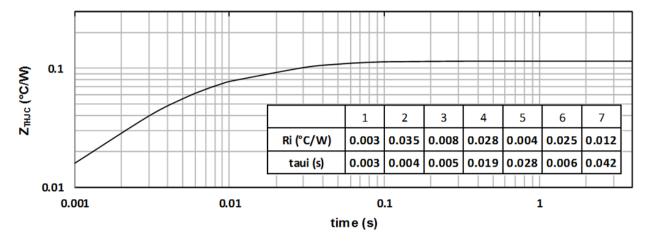


Figure 2 • Forward Current vs. Forward Voltage

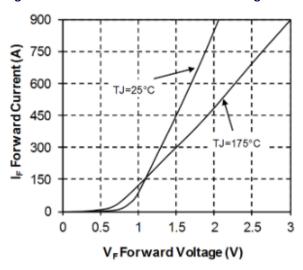
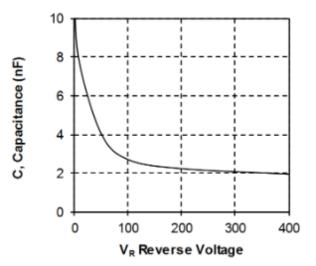


Figure 3 • Capacitance vs. Reverse Voltage





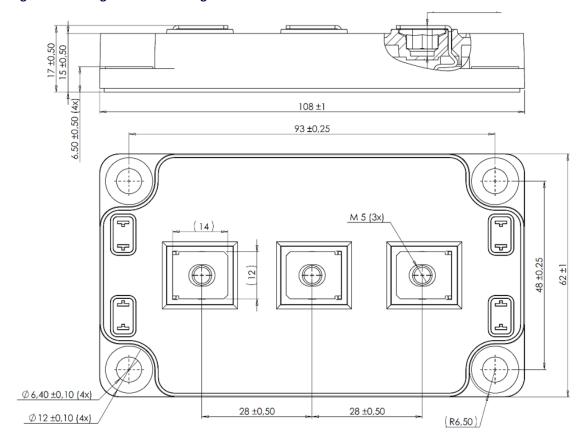
3 Package Specifications

This section shows the package specifications for the MSCDC450A70AG device.

3.1 Package Outline Drawing

The following drawing shows the package outline of the MSCDC450A70AG device. The dimensions in the following figure are in millimeters.

Figure 4 • Package Outline Drawing







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MSCC-0344-DS-01021 | June 2019 | Final

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